

EMIF06-HSD03F3

EMI filter with integrated ESD protection for micro-SD Card™

Datasheet - production data

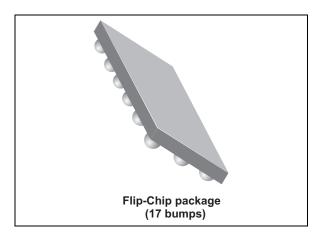


Figure 1. Pin configuration (bump side)

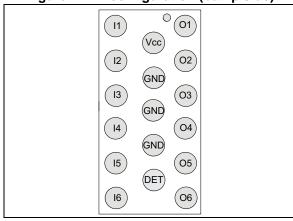
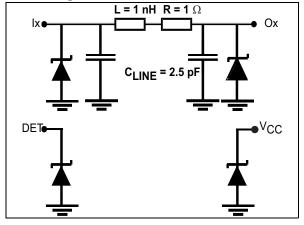


Figure 2. Functional schematic



Features

- Very low line capacitance to compensate long PCB tracks (2.5 pF typ.)
- High efficiency in ESD suppression up to 18 kV (IEC 61000-4-2)
- Very low PCB space consumption:
 - 1.1 x 2.4 mm
- Ultralow leakage current: 20 nA max.
- Very thin package: 0.605 mm
- · Smart pinout for easier PCB layout
- High reduction of parasitic elements through integration and wafer level packaging
- · Lead-free package
- Complies with the following standards:
 - IEC 61000-4-2 level 4:±15 kV (air discharge), ±8 kV (contact discharge)

Application

• SD3.0, UHS-1 SDR104 (208 MHz)

Description

The EMIF06-HSD03F3 chip is a highly integrated device designed to suppress EMI/RFI noise for interface line filtering.

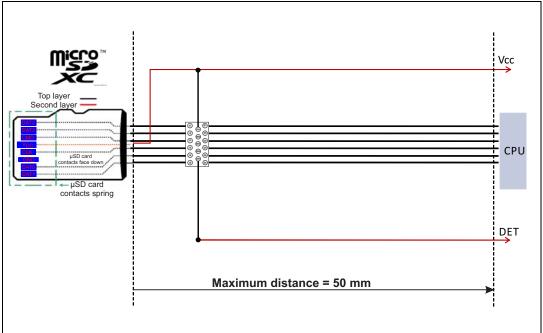
The EMIF06-HSD03F3 Flip-Chip packaging means the package size is equal to the die size. That's why EMIF06-HSD03F3 is a very small device. Additionally, this filter includes ESD protection circuitry, which prevents damage to the protected device when subjected to ESD surges up 18 kV.

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Application diagram EMIF06-HSD03F3

1 Application diagram

Figure 3. Schema



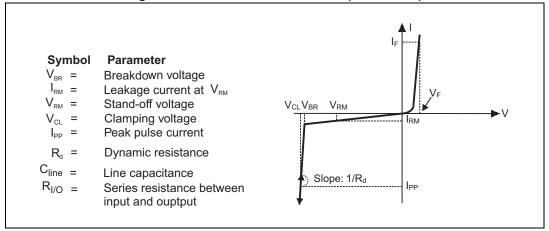
EMIF06-HSD03F3 Characteristics

2 Characteristics

Table 1. Absolute maximum ratings ($T_{amb} = 25 \text{ °C}$)

Symbol	Parameter	Value	Unit
V _{PP}	ESD discharge IEC 61000-4-2, level 4 for Ix pins: Air discharge Contact discharge ESD discharge IEC 61000-4-2, level 1 for Ox pins: Air discharge Contact discharge	18 18 10 10	kV
T _j	Maximum junction temperature	125	°C
T _{OP}	Operating temperature range	- 30 to + 85	°C
T _{stg}	Storage temperature range	- 55 to +150	°C

Figure 4. Electrical characteristics (definitions)

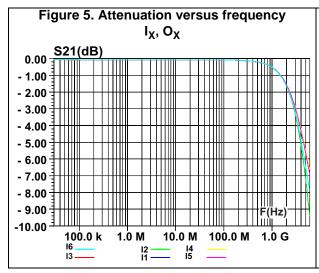


Characteristics EMIF06-HSD03F3

Table 2. Electrical characteristics (T_{amb} = 25 °C)

Symbol	Test conditions		Min.	Тур.	Max.	Unit
V_{BR}	Data lines, I _R = 1 mA		5		9	V
I _{RM}	V _{RM} = 3 V per line				20	nA
R _{I/O}				1		Ω
C _{line}	$V_{line} = 0 \text{ V}, V_{osc} = 30 \text{ mV}, F = 1 \text{ MHz}$			2.5	3	pF
L				1		nΗ
Rd		O-GND (positive polarity)		650		- m Ω
	Dynamics resistance, t _P = 100 ns GND-IO (negative polari	SND-IO (negative polarity)		320		
V _{CC}						
V_{BR}	I _R = 1 mA		5		9	V
I _{RM}	V _{RM} = 3 V				20	nA
C _{line}	V _{line} = 0 V, V _{OSC} = 30 mV, F = 1 MHz			40		pF
DET						
V_{BR}	I _R = 1 mA		5		9	V
I _{RM}	V _{RM} = 3 V		·		20	nA
C _{line}	$V_{line} = 0 \text{ V}, V_{osc} = 30 \text{ mV}, F = 1 \text{ MHz}$		·	40		pF

EMIF06-HSD03F3 Characteristics



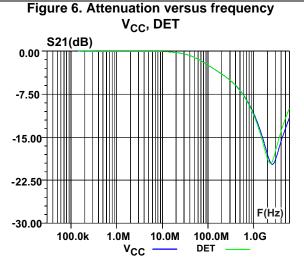


Figure 7. ESD response to IEC 61000-4-2 (+8 kV contact discharge)

20.0 V / Div

Ova: Peak clamping voltage
Ova: clamping voltage @ 30 ns
Ova: clamping voltage @ 60 ns
Ova: clamping voltage @ 100 ns
Ova: clamping voltage @ 100 ns

Figure 8. ESD response to IEC 61000-4-2 (-8 kV contact discharge)

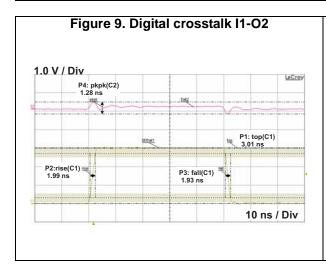
10.0 V / Div

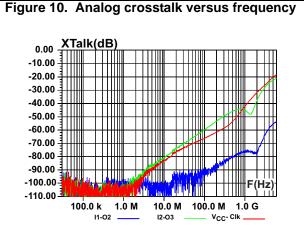
2-5.1 V 3-4.1 V 2-2.4 V

Vol.: Peak clamping voltage 2 Vc.: clamping voltage 2 Vc.: clamping voltage 2 Vc.: clamping voltage 2 Vc.: clamping voltage 2 100 ns

Vol.: Clamping voltage 2 100 ns

Vol.: Clamping voltage 2 100 ns





Characteristics EMIF06-HSD03F3

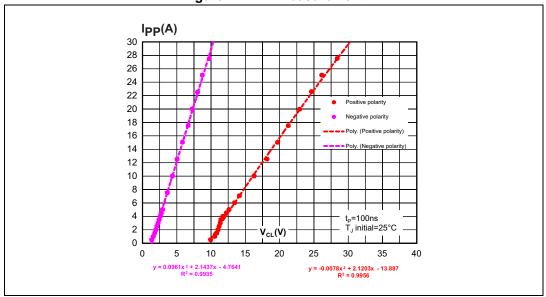


Figure 11. TLP measurement

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3 Package information

- Epoxy meets UL94, V0
- Lead-free package

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3.1 Flip-Chip package information

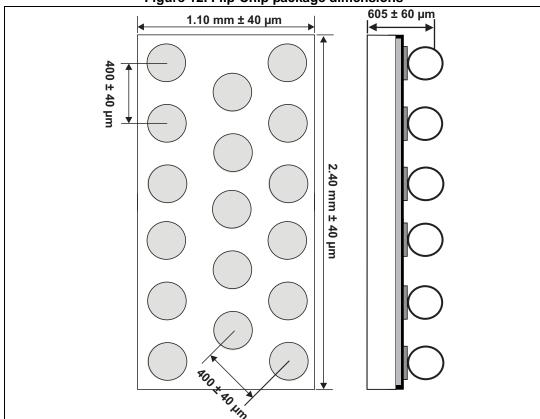


Figure 12. Flip-Chip package dimensions

Package information EMIF06-HSD03F3

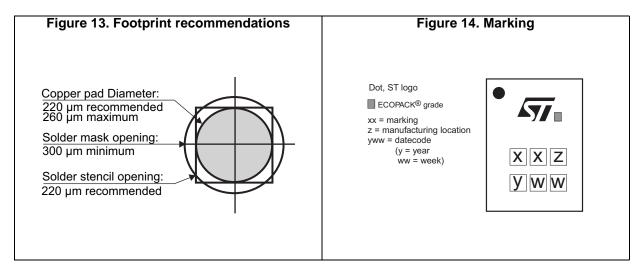
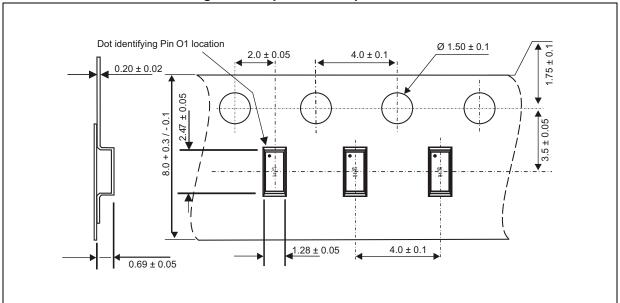


Figure 15. Tape and reel specification



Note: More information is available in the application notes:

AN2348, "IPAD™ 400 µm Flip Chip: package description and recommendations for use"

AN1751, "EMI filters: recommendations and measurements"

AN4541: "EMI Filters for SD3.0 card: High speed SD card protection and filtering devices"

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4 Ordering information

Figure 16. Ordering information scheme

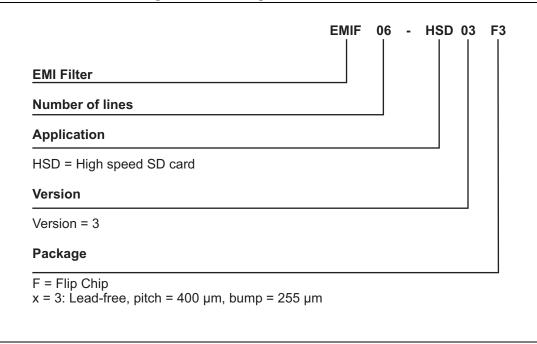


Table 3. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
EMIF06-HSD03F3	KK	Flip Chip	3.4 mg	5000	Tape and reel (7")

5 Revision history

Table 4. Document revision history

Date	Revision	Changes
19-Nov-2013	1	Initial release
09-Jan-2014	2	Corrected typographical error.
06-Jan-2015	3	Added mention for new AN4541.
06-Oct-2016		Updated Figure 1.

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